



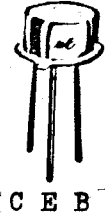
# 2N3019

# 2N3020

NPN SILICON AF MEDIUM POWER AMPLIFIERS & SWITCHES

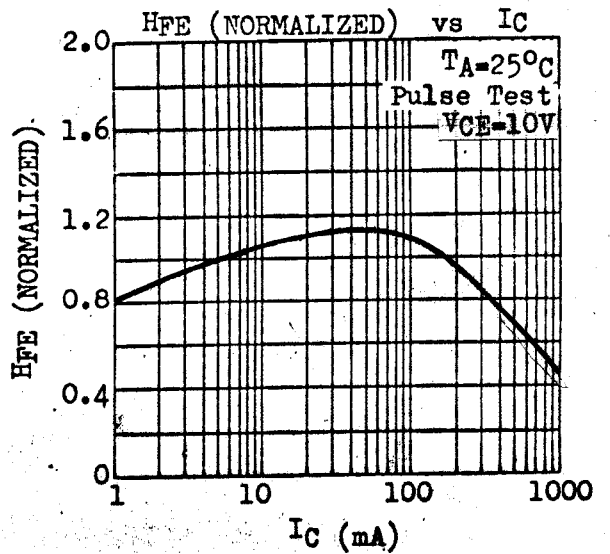
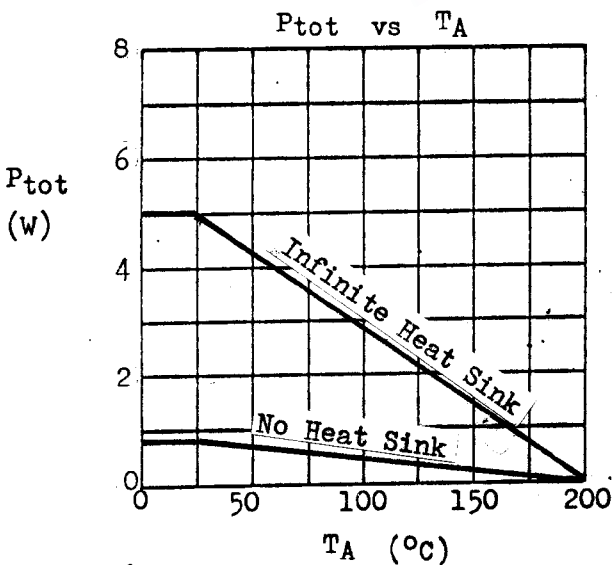
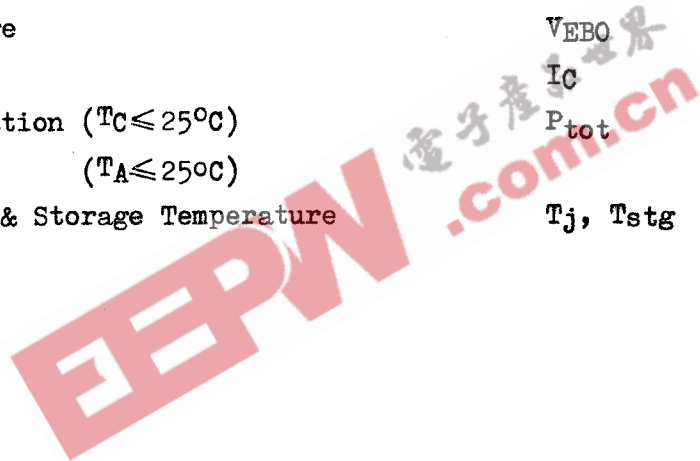
CASE TO-39

THE 2N3019, 2N3020 ARE NPN SILICON PLANAR EPITAXIAL TRANSISTORS FOR AF MEDIUM POWER DRIVERS AND OUTPUTS, AS WELL AS FOR SWITCHING APPLICATIONS UP TO 1 AMPERE. THEY ARE COMPLEMENTARY TO THE PNP 2N4033, 2N4031.



### ABSOLUTE MAXIMUM RATINGS

Collector-Base Voltage	VCBO	140V
Collector-Emitter Voltage	VCEO	80V
Emitter-Base Voltage	VEBO	7V
Collector Current	IC	1A
Total Power Dissipation (Tc ≤ 25°C)	Ptot	5W
(TA ≤ 25°C)		800mW
Operating Junction & Storage Temperature	Tj, Tstg	-65 to 200°C



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ELECTRICAL CHARACTERISTICS ( $T_A=25^{\circ}C$  unless otherwise noted)

PARAMETER	SYMBOL	2N3019		2N3020		UNIT	TEST CONDITIONS
		MIN	MAX	MIN	MAX		
Collector-Base Breakdown Voltage	BVCBO	140		140		V	$I_C=0.1mA$ $I_E=0$
Collector-Emitter Breakdown Voltage	LVCEO *	80		80		V	$I_C=30mA$ $I_B=0$
Emitter-Base Breakdown Voltage	BVEBO	7		7		V	$I_E=0.1mA$ $I_C=0$
Collector Cutoff Current	ICBO		10		10	nA	$V_{CB}=90V$ $I_E=0$
			10		10	$\mu A$	$V_{CB}=90V$ $I_E=0$ $T_A=150^{\circ}C$
Emitter Cutoff Current	IEBO		10		10	nA	$V_{EB}=5V$ $I_C=0$
Collector-Emitter Saturation Voltage	VCE(sat)*		0.2		0.2	V	$I_C=150mA$ $I_B=15mA$
			0.5		0.5	V	$I_C=500mA$ $I_B=50mA$
Base-Emitter Saturation Voltage	VBE(sat)*		1.1		1.1	V	$I_C=150mA$ $I_B=15mA$
D.C. Current Gain	HFE *	50		30	100		$I_C=0.1mA$ $V_{CE}=10V$
		90		40	120		$I_C=10mA$ $V_{CE}=10V$
		100	300	40	120		$I_C=150mA$ $V_{CE}=10V$
		50		30	100		$I_C=500mA$ $V_{CE}=10V$
		15		15			$I_C=1A$ $V_{CE}=10V$
		40					$I_C=150mA$ $V_{CE}=10V$ $T_A=-55^{\circ}C$
Current Gain-Bandwidth Product	$f_T$	100		80		MHz	$I_C=50mA$ $V_{CE}=10V$
Collector-Base Capacitance	Cob		12		12	pF	$V_{CB}=10V$ $I_E=0$
Emitter-Base Capacitance	Cib		60		60	pF	$V_{EB}=0.5V$ $I_C=0$ $f=1MHz$
Collector-Base Time Constant	$\tau_{cb}$		400		400	pS	$I_C=10mA$ $V_{CE}=10V$ $f=4MHz$
Noise Figure	NF		4			dB	$I_C=0.1mA$ $V_{CE}=10V$ $R_G=1K\Omega$ $f=1kHz$
Small Signal Current Gain ( $f=1kHz$ )	$h_{fe}$	80	400	30	200		$I_C=1mA$ $V_{CE}=5V$

\* Pulse Test : Pulse Width=0.3mS, Duty Cycle=1%

